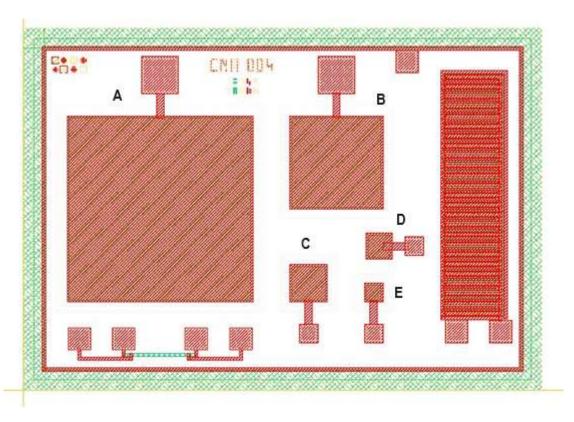
ANNEX I. Formulas

Value Description

Units

Cmax	Maximum capacity, obtained as an average of the last five values pF		
	of the curve in accumulation situation, equivalent to the capacity		
	of the oxide (C_{ox}) .		
Cmin	Minimum capacity, obtained as the minimum value of the curve.	pF	
Dox	Oxide thickness.	Å	
	$d_{ox} = \frac{\varepsilon_0 \cdot \varepsilon_{ox} \cdot S}{c_{max}}$		
Na	Substrate doping.	cm ⁻³	
	$ln\left(\frac{Na}{n_i}\right) - \frac{q2 \cdot ni \cdot W_m^2}{4 \cdot \varepsilon_S \cdot k \cdot T} \left(\frac{Na}{n_i}\right) = 0$		
	$W_m = \varepsilon_S \cdot \left(\frac{1}{C_{min}^{HF}} - \frac{1}{C_{max}}\right)$		
V_{FB}	Flat band voltage is the voltage for which the capacity is equal to V		
	the capacity of flat band (C _{FB}).		
	$C_{FB} = \frac{1}{\frac{1}{C_{ox}} + \frac{1}{C_{s_{FB}}}}$ $C_{s_{FB}} = \sqrt{\frac{q^2 \cdot \varepsilon_S \cdot N_A}{k \cdot T}}$		
Nss	Total charge density on the insulator.	cm ⁻²	
1	l I		
	$Nss = (\Phi_{MS} - V_{FB}) \cdot \frac{c_{ox}}{q \cdot S}$		
Rs	$Nss = (\Phi_{MS} - V_{FB}) \cdot \frac{c_{ox}}{q \cdot S}$ Serial resistance.	Ω	
Rs	ų s	Ω	
Rs	Serial resistance.	Ω	
Rs	Serial resistance. $R_S = \frac{G_{acc}}{G_{acc}^2 + w^2 \cdot C_{acc}^2}$ $G_{acc}, C_{acc} = \text{Accumulation conductance and capacitance}$	Ω	
Rs	Serial resistance. $R_S = \frac{G_{acc}}{G_{acc}^2 + w^2 \cdot C_{acc}^2}$ $G_{acc}, C_{acc} = \text{Accumulation conductance and capacitance}$ Then the measured capacitance (C _m) and the measured	Ω	
Rs	Serial resistance. $R_S = \frac{G_{acc}}{G_{acc}^2 + w^2 \cdot C_{acc}^2}$ $G_{acc}, C_{acc} = \text{Accumulation conductance and capacitance}$	Ω	
Rs	Serial resistance. $R_{\mathcal{S}} = \frac{G_{acc}}{G_{acc}^2 + w^2 \cdot C_{acc}^2}$ $G_{acc}, C_{acc} = \text{Accumulation conductance and capacitance}$ Then the measured capacitance (C _m) and the measured conductance (G _m) are compensated for this obtained value of R _S	Ω	

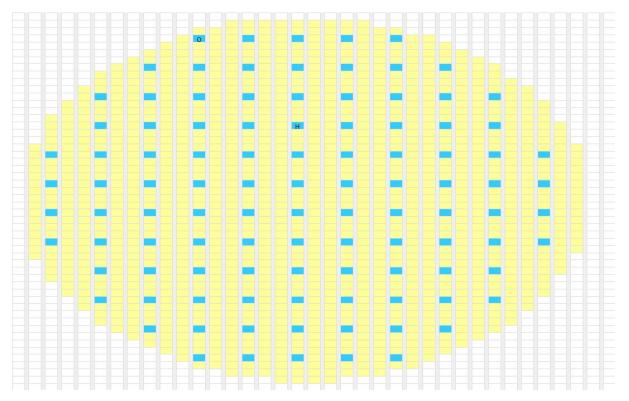
ANNEX II. Layout information CNM004



 $\begin{tabular}{ll} \textbf{Layout capacitance chip} \\ \textbf{Chip overall dimensions are X=2790 } \mu m, \ Y=1950 \ \mu m. \end{tabular}$

CAP	Area (μm²)
A	980x980
В	480x480
C	180x180
D	120x120
Е	80x80

ANNEX III. Wafermap file



Wafermap used in cartography

Total of 104 capacitances